HD74LVC138

3-to-8-line Decoder / Demultiplexer

HITACHI

Description

The HD74LVC138 has three binary select inputs in a 16 pin package. If the device is enabled these inputs determine which one of the eight normally high outputs will go low. Two active low and one active high enables are provided to ease the cascading of decoders. Low voltage and high speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- V_{CC} = 2.0 V to 5.5 V
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V)
- Typical V_{OL} ground bounce < 0.8 V (@V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@V_{CC} = 3.3 V, Ta = 25°C)
- High output current ±24 mA (@V_{CC} = 3.0 V to 5.5 V)

HD74LVC138

Function Table

Enable			Select			Outputs							
G_1	G_{2A}	G_{2B}	C	B	A	Y_0	Y_1	Y_2	Y_3	Y_4	Y_5	Y_6	Y_7
X	X	H	X	X	X	H	H	H	H	H	H	H	H
X	H	X	X	X	X	H	H	H	H	H	H	H	H
L	X	X	X	X	X	H	H	H	H	H	H	H	H
H	L	L	L	L	L	L	H	H	H	H	H	H	H
H	L	L	L	L	H	H	L	H	H	H	H	H	H
H	L	L	L	H	L	H	H	L	H	H	H	H	H
H	L	L	L	H	H	H	H	H	L	H	H	H	H
H	L	L	H	L	L	H	H	H	H	L	H	H	H
H	L	L	H	L	H	H	H	H	H	H	L	H	H
H	L	L	H	H	L	H	H	H	H	H	H	L	H
H	L	L	H	H	H	H	H	H	H	H	H	H	L

H : High level
L : Low level
X : Immaterial

Pin Arrangement

(Top view)

HITACHI
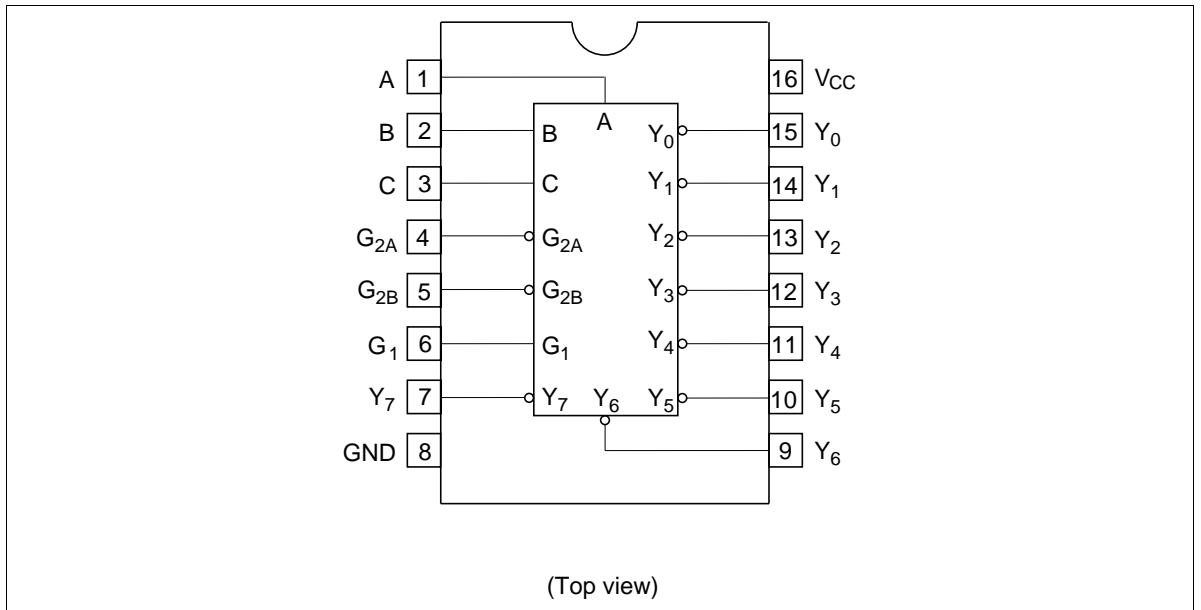
Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	−0.5 to 6.0	V	
Input diode current	I_{IK}	−50	mA	$V_I = −0.5$ V
Input voltage	V_I	−0.5 to 6.0	V	
Output diode current	I_{OK}	−50	mA	$V_O = −0.5$ V
		50	mA	$V_O = V_{CC} +0.5$ V
Output voltage	V_O	−0.5 to V_{CC} +0.5	V	
Output current	I_O	±50	mA	
V_{CC}, GND current / pin	I_{CC} or I_{GND}	100	mA	
Storage temperature	Tstg	−65 to +150	°C	

Note: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	1.5 to 5.5	V	Data retention
		2.0 to 5.5	V	At operation
Input / output voltage	V_I	0 to 5.5	V	G, A, B, C
	V_O	0 to V_{CC}	V	Y_0 to Y_7
Operating temperature	Ta	−40 to 85	°C	
Output current	I_{OH}	−12	mA	$V_{CC} = 2.7$ V
		−24[2]	mA	$V_{CC} = 3.0$ V to 5.5 V
	I_{OL}	12	mA	$V_{CC} = 2.7$ V
		24[2]	mA	$V_{CC} = 3.0$ V to 5.5 V
Input rise / fall time [1]	t_r, t_f	10	ns/V	

Notes: 1. This item guarantees maximum limit when one input switches.

   Waveform : Refer to test circuit of switching characteristics.
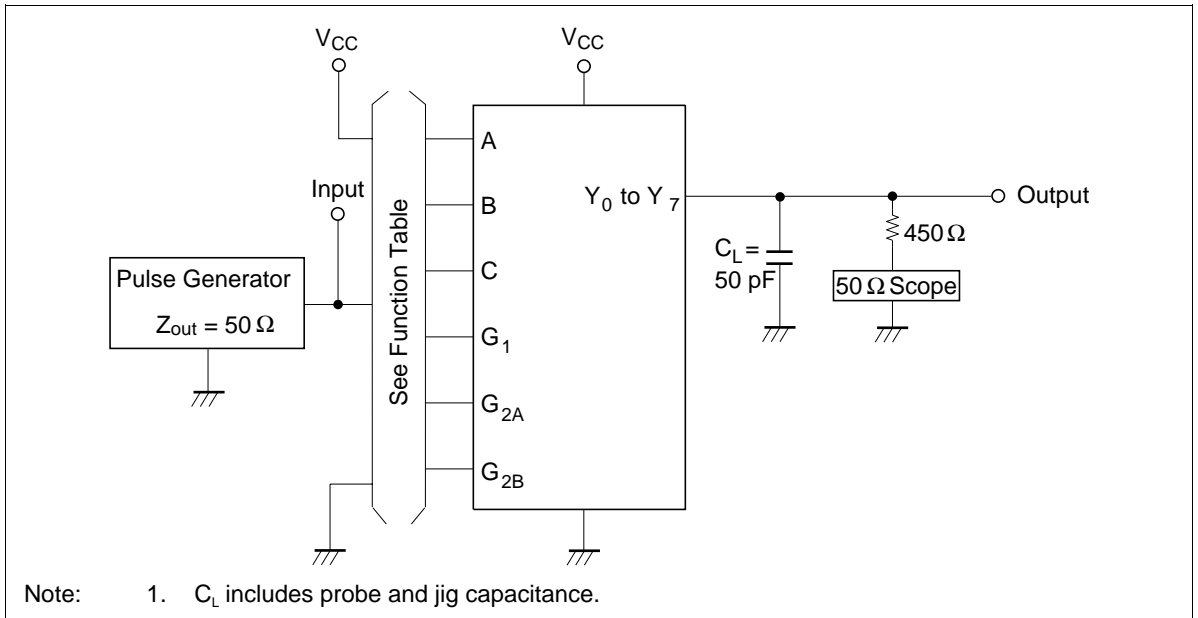
   2. duty cycle ≤ 50%

HITACHI

Electrical Characteristics

Item	Symbol	V_{CC} (V)	Ta = −40 to 85°C Min	Max	Unit	Test Conditions
Input voltage	V_{IH}	2.7 to 3.6	2.0	—	V	
		4.5 to 5.5	$V_{CC}×0.7$	—	V	
	V_{IL}	2.7 to 3.6	—	0.8	V	
		4.5 to 5.5	—	$V_{CC}×0.3$	V	
Output voltage	V_{OH}	2.7 to 5.5	V_{CC} −0.2	—	V	I_{OH} = −100 μA
		2.7	2.2	—	V	I_{OH} = −12 mA
		3.0	2.4	—	V	
		3.0	2.0	—	V	I_{OH} = −24 mA
		4.5	3.8	—	V	
	V_{OL}	2.7 to 5.5	—	0.2	V	I_{OL} = 100 μA
		2.7	—	0.4	V	I_{OL} = 12 mA
		3.0	—	0.55	V	I_{OL} = 24 mA
		4.5	—	0.55	V	
Input current	I_{IN}	0 to 5.5	—	±5.0	μA	V_{IN} = 5.5 V or GND
Quiescent supply current	I_{CC}	5.5	—	20	μA	V_{IN} = V_{CC} or GND
	ΔI_{CC}	3.0 to 3.6	—	500	μA	V_{IN} = one input at(V_{CC} −0.6)V, other inputs at V_{CC} or GND

Switching Characteristics

Item	Symbol	V_{CC} (V)	Ta = −40 to 85°C Min	Typ	Max	Unit	From (Input)	To (Output)
Propagation delay time	t_{PLH}	2.7	—	7.0	10.0	ns	G, A, B, C	Y_0 to Y_7
	t_{PHL}	3.3±0.3	1.5	5.0	9.0	ns		
		5.0±0.5	—	3.5	7.5	ns		
Input capacitance	C_{IN}	2.7	—	3.0	—	pF		
Output capacitance	C_O	2.7	—	15.0	—	pF		

HITACHI

Test Circuit

Note: 1. C_L includes probe and jig capacitance.
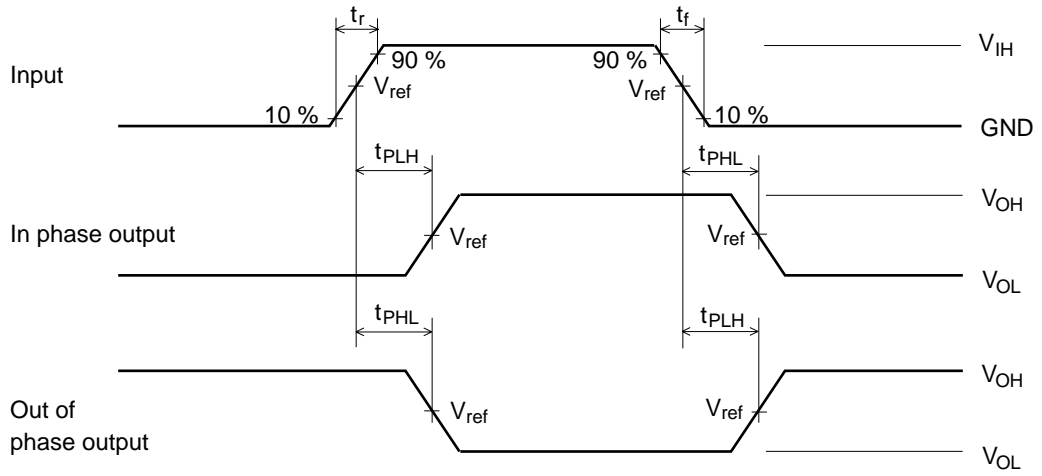
Waveforms

Symbol	$V_{CC} = 2.7\ V,$ $3.3 \pm 0.3\ V$	$V_{CC} = 5.0 \pm 0.5\ V$
V_{IH}	2.7 V	V_{CC}
V_{ref}	1.5 V	50%V_{CC}

Notes: 1. t_r = 2.5 ns, t_f = 2.5 ns
            2.   Input waveform : PRR = 10 MHz, duty cycle 50%

HITACHI

Unit: mm

Hitachi Code	TTP-16DA
JEDEC	—
EIAJ	—
Weight (reference value)	0.05 g
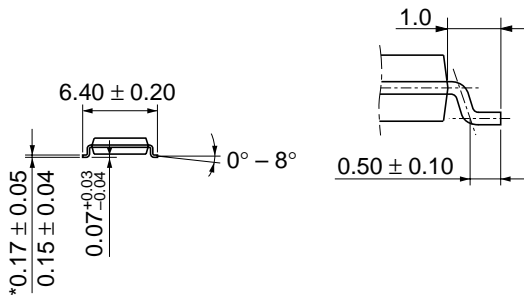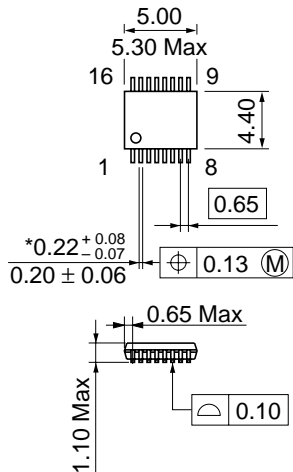
*Dimension including the plating thickness
Base material dimension

Cautions

1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.

2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.

3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.

4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.

5. This product is not designed to be radiation resistant.

6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.

7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

HITACHI

Hitachi, Ltd.
Semiconductor & Integrated Circuits.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL		
	NorthAmerica	: http:semiconductor.hitachi.com/
	Europe	: http://www.hitachi-eu.com/hel/ecg
	Asia (Singapore)	: http://www.has.hitachi.com.sg/grp3/sicd/index.htm
	Asia (Taiwan)	: http://www.hitachi.com.tw/E/Product/SICD_Frame.htm
	Asia (HongKong)	: http://www.hitachi.com.hk/eng/bo/grp3/index.htm
	Japan	: http://www.hitachi.co.jp/Sicd/indx.htm

For further information write to:

Hitachi Semiconductor
(America) Inc.
179 East Tasman Drive,
San Jose,CA 95134
Tel: <1> (408) 433-1990
Fax: <1>(408) 433-0223

Hitachi Europe GmbH
Electronic components Group
Dornacher Straße 3
D-85622 Feldkirchen, Munich
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.
Electronic Components Group.
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA, United Kingdom
Tel: <44> (1628) 585000
Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd.
16 Collyer Quay #20-00
Hitachi Tower
Singapore 049318
Tel: 535-2100
Fax: 535-1533

Hitachi Asia Ltd.
Taipei Branch Office
3F, Hung Kuo Building. No.167,
Tun-Hwa North Road, Taipei (105)
Tel: <886> (2) 2718-3666
Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower, World Finance Centre,
Harbour City, Canton Road, Tsim Sha Tsui,
Kowloon, Hong Kong
Tel: <852> (2) 735 9218
Fax: <852> (2) 730 0281
Telex: 40815 HITEC HX

HITACHI